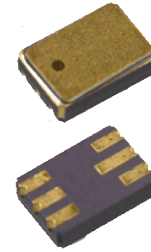


# Surface Mount Optically Coupled Isolator

4N22U, 4N23U, 4N24U (TX, TXV)  
4N47U, 4N48U, 4N49U (TX, TXV)



## Features:

- Surface Mount (SM), Leadless Chip Carrier (LCC)
- 1 kV electrical isolation
- Base contact provided for conventional transistor biasing

## Description:

Each isolator in this series consists of an infrared emitting diode and a NPN silicon phototransistor, which are mounted in a hermetically sealed Surface Mount, 6 Pin package. Devices are designed for military and/or harsh environments.

The 4N22U, 4N23U and 4N24U (TX, TXV) devices are processed to MIL-PRF-19500/486. The 4N47U, 4N48U and 4N49U (TX, TXV) devices are processed to MIL-PRF-19500/548.

Please contact your local representative or OPTEK for more information.

## Applications:

- Military equipment
- High-Reliability environments
- High voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment

Ordering Information				
Part Number	Isolation Voltage (kV)	I <sub>F</sub> (mA) Typ / Max	V <sub>CE</sub> (Volts) Max	Processing MIL-PRF-195000
4N22U	1	10 / 40	35	486
4N22UTX				
4N22UTXV				
4N23U				
4N23UTX				
4N23UTXV				
4N24U			45	548
4N24UTX				
4N24UTXV				
4N47U				
4N47UTX				
4N47UTXV				
4N48U				
4N48UTX				
4N48UTXV				
4N49U				
4N49UTX				
4N49UTXV				

### General Note

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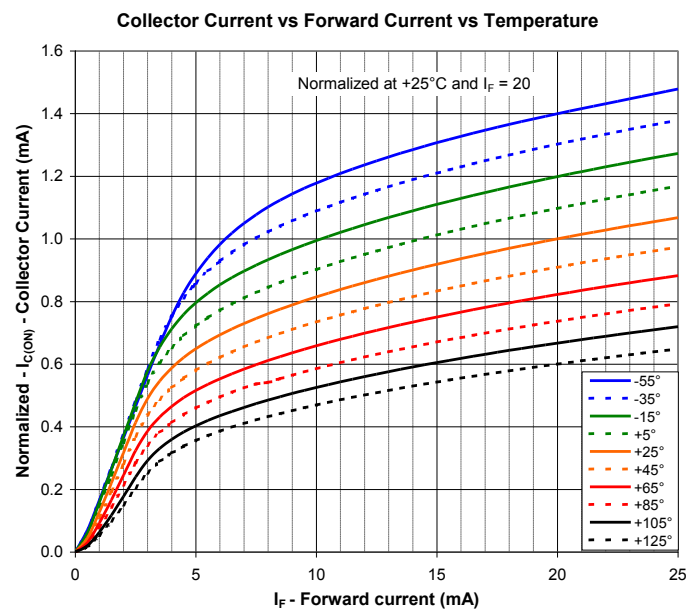
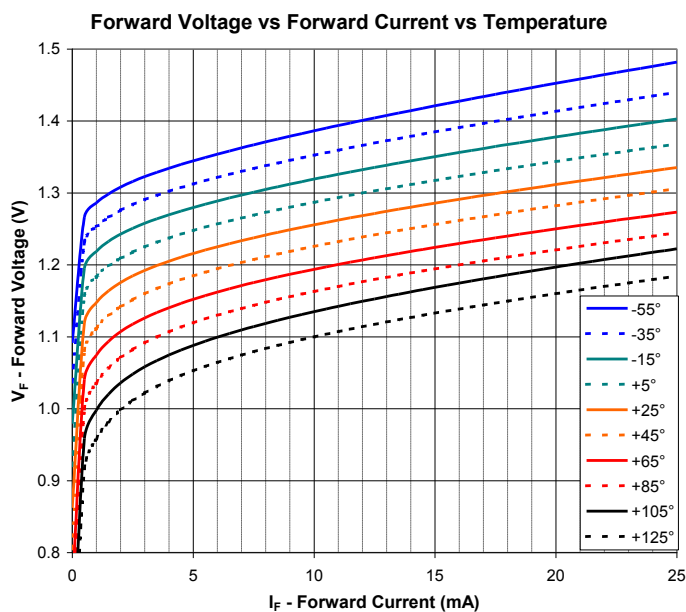
4N22U, 4N23U, 4N24U (TX, TXV)  
4N47U, 4N48U, 4N49U (TX, TXV)



Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ unless otherwise noted)	
Storage Temperature	-65° C to +150° C
Operating Temperature	-55° C to +125° C
Input-to-Output Isolation Voltage <sup>(1)</sup>	± 1 kVDC
Lead Soldering Temperature (1/16" (1.6 mm) from case for 5 seconds with soldering iron) <sup>(2)</sup>	260° C
<b>Input Diode</b>	
Forward DC Current <sup>(3)</sup>	50 mA
Reverse DC Voltage	2 V
Power Dissipation <sup>(4)</sup>	100 mW
<b>Output Photosensor</b>	
Collector-Emitter Voltage	35 V
Emitter-Collector Voltage	7.0 V
Power Dissipation <sup>(5)</sup>	300 mW

**Notes:**

- (1) Measured with input leads shorted together and output leads shorted together. Typical input/output capacitance is 0.06 pF.
- (2) RMA flux is recommended. The duration can be extended to 10 seconds maximum when flow soldering.
- (3) Derate linearly 0.67 mW/°C above 65°C.
- (4) Derate linearly 0.83 mW/°C above 25°C.
- (5) Derate linearly 1.67 mW/°C above 25°C.



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4N22U, 4N23U, 4N24U (TX, TXV)  
4N47U, 4N48U, 4N49U (TX, TXV)



## Electrical Characteristics (T<sub>A</sub> = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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### Input LED

V <sub>F</sub>	Forward Voltage					
	4N22U, 4N23U, 4N24U (TX, TXV)	0.80	-	1.30		I <sub>F</sub> = 10.0 mA
	4N22U, 4N23U, 4N24U (TX, TXV)	1.00	-	1.50		I <sub>F</sub> = 10.0 mA, T <sub>A</sub> = -55° C <sup>(1)</sup>
	4N22U, 4N23U, 4N24U (TX, TXV)	0.70	-	1.20	V	I <sub>F</sub> = 10.0 mA, T <sub>A</sub> = -100° C <sup>(1)</sup>
	4N47U, 4N48U, 4N49U (TX, TXV)	0.80	-	1.50		I <sub>F</sub> = 10.0 mA
	4N47U, 4N48U, 4N49U (TX, TXV)	1.00	-	1.70		I <sub>F</sub> = 10.0 mA, T <sub>A</sub> = -55° C <sup>(1)</sup>
	4N47U, 4N48U, 4N49U (TX, TXV)	0.70	-	1.30		I <sub>F</sub> = 10.0 mA, T <sub>A</sub> = -100° C <sup>(1)</sup>
I <sub>R</sub>	Reverse Current	-	-	100	μA	V <sub>R</sub> = 2.0 V

### Output Phototransistor

V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage 4N22U Series 4N47U Series	35 40	80 90	- -	V	I <sub>C</sub> = 100 μA, I <sub>F</sub> = 0
V <sub>(BR)ECO</sub>	Emitter-Collector Breakdown Voltage 4N22U Series 4N47U Series	4 7	6 10	- -	V	I <sub>E</sub> = 100 μA, I <sub>F</sub> = 0
I <sub>CEO</sub>	Collector-Emitter Dark Current	- -	20 -	100 100	nA μA	V <sub>CE</sub> = 20 V, I <sub>F</sub> = 0 I <sub>B</sub> = 0 T <sub>A</sub> = 25° C V <sub>CE</sub> = 20 V, I <sub>F</sub> = 0 I <sub>B</sub> = 0 T <sub>A</sub> = 100° C
V <sub>CE(SAT)</sub>	Collector Saturation Voltage	-	0.2	0.3	V	I <sub>F</sub> = 20 mA, I <sub>C</sub> = 2 mA

Notes:

- (1) Measured with input leads shorted together and output leads shorted together. Typical input/output capacitance is 0.06 pF.



Pin #	LED	Pin #	Transistor
2	N/A	3	Collector
1	Anode	4	Base
6	Cathode	5	Emitter

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4N22U, 4N23U, 4N24U (TX, TXV)  
4N47U, 4N48U, 4N49U (TX, TXV)



SYMBOL	PARAMETER	PART NUMBER	MIN	TYP	MAX	UNITS	TEST CONDITIONS		
<b>Coupled</b>									
$I_C/I_F$	DC Current Transfer Ratio	4N22U	25	-	-	%	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$		
		4N23U	60	-	-				
		4N24U	100	-	-	%	$I_F = 2 \text{ mA}, V_{CE} = 5 \text{ V}$		
		4N47U	50	-	-				
		4N48U	100	-	-				
		4N49U	200	-	-				
$I_{C(ON)}$	On-State Collector Current	4N22U	0.15	-	-	mA	$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = 25^\circ\text{C}$		
			2.50	-	-		$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = 25^\circ\text{C}$		
			1.00	-	-		$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = -55^\circ\text{C}$		
				4N23U	0.2	-	-	mA	$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = 25^\circ\text{C}$
					6.0	-	-		$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = 25^\circ\text{C}$
					2.5	-	-		$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = -55^\circ\text{C}$
				4N24U	2.5	-	-	mA	$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = 100^\circ\text{C}$
		0.4	-		-	$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = 25^\circ\text{C}$			
		4N47U	10.0	-	-	mA	$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = 25^\circ\text{C}$		
			4.0	-	-		$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = -55^\circ\text{C}$		
		4N48U	4.0	-	-	mA	$V_{CE} = 10 \text{ V}, I_B = 0, I_F = 10.0 \text{ mA } T_A = 100^\circ\text{C}$		
			0.5	-	-		$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 1.0 \text{ mA } T_A = 25^\circ\text{C}$		
			0.7	-	-		$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = -55^\circ\text{C}$		
		4N49U	0.5	-	-	mA	$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = 100^\circ\text{C}$		
			1.0	-	5.0		$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 1.0 \text{ mA } T_A = 25^\circ\text{C}$		
		4N49U	1.4	-	-	mA	$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = -55^\circ\text{C}$		
			1.0	-	-		$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = 100^\circ\text{C}$		
		4N49U	2.0	-	10.0	mA	$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 1.0 \text{ mA } T_A = 25^\circ\text{C}$		
			2.8	-	-		$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = -55^\circ\text{C}$		
		4N49U	2.0	-	-		$V_{CE} = 5 \text{ V}, I_B = 0, I_F = 2.0 \text{ mA } T_A = 100^\circ\text{C}$		
$V_{CE(SAT)}$	Collector Saturation Voltage	4N22U	-	-	0.3	V	$I_C = 2.5 \text{ mA}, I_B = 0, I_F = 20 \text{ mA}$		
		4N23U	-	-	0.3		$I_C = 5.0 \text{ mA}, I_B = 0, I_F = 20 \text{ mA}$		
		4N24U	-	-	0.3		$I_C = 10.0 \text{ mA}, I_B = 0, I_F = 20 \text{ mA}$		
		4N47U	-	-	0.3	V	$I_C = 0.5 \text{ mA}, I_B = 0, I_F = 2.0 \text{ mA}$		
		4N48U	-	-	0.3		$I_C = 1.0 \text{ mA}, I_B = 0, I_F = 2.0 \text{ mA}$		
4N49U	-	-	0.3		$I_C = 2.0 \text{ mA}, I_B = 0, I_F = 2.0 \text{ mA}$				
$h_{FE}$	DC Current Gain	4N22U	200	-	-	-	$V_{CE} = 5 \text{ V}, I_C = 10 \text{ mA}, I_F = 0 \text{ mA}$		
		4N23U	300	-	-				
		4N24U	400	-	-				
		4N47U	100	-	-				
		4N48U	100	-	-				
4N49U	100	-	-						
$t_r$ & $t_f$	Rise and Fall Time	4N22U	-	-	15	$\mu\text{s}$	$V_{CC} = 10 \text{ V}, I_F = 10 \text{ mA}, R_L = 100\Omega,$ Pulse width = 100 ms, Duty cycle = 1%		
		4N23U	-	-	15				
		4N24U	-	-	20				
		4N47U	-	-	20	$\mu\text{s}$	$V_{CC} = 10 \text{ V}, I_F = 5 \text{ mA}, R_L = 100\Omega,$ Pulse width = 100 ms, Duty cycle = 1%		
		4N48U	-	-	20				
4N49U	-	-	20						
$R_{IO}$	Resistance (Input to Output)		$10^{11}$	-	-	$\Omega$	$V_{I-O} = \pm 1,000 \text{ Vdc}$		
$C_{IO}$	Capacitance (Input to Output)		-	-	5.0	pF	$V_{I-O} = 0 \text{ Vdc}, f = 1.0 \text{ MHz}$		

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4N22U, 4N23U, 4N24U (TX, TXV)  
4N47U, 4N48U, 4N49U (TX, TXV)



## Electrical Characteristics (T<sub>A</sub> = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
I <sub>C(ON)</sub>	On-State Collector Current					
	4N22U, 4N22U (TX, TXV)	0.15	-	-	mA	I <sub>F</sub> = 2.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0
	4N22U, 4N22U (TX, TXV)	2.50	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0
	4N22U, 4N22U (TX, TXV)	1.00	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0, T <sub>A</sub> = -55° C <sup>(1)</sup>
	4N22U, 4N22U (TX, TXV)	1.00	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0, T <sub>A</sub> = 100° C <sup>(1)</sup>
	4N23U, 4N23U (TX, TXV)	0.20	-	-		I <sub>F</sub> = 2.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0
	4N23U, 4N23U (TX, TXV)	6.00	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0
	4N23U, 4N23U (TX, TXV)	2.50	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0, T <sub>A</sub> = -55° C <sup>(1)</sup>
	4N23U, 4N23U (TX, TXV)	2.50	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0, T <sub>A</sub> = 100° C <sup>(1)</sup>
	4N24U, 4N24U (TX, TXV)	0.40	-	-		I <sub>F</sub> = 2.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0
	4N24U, 4N24U (TX, TXV)	10.0	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0
	4N24U, 4N24U (TX, TXV)	4.00	-	-		I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0, T <sub>A</sub> = -55° C <sup>(1)</sup>
4N24U, 4N24U (TX, TXV)	4.00	-	-	I <sub>F</sub> = 10.0 mA, V <sub>CE</sub> = 5 V, I <sub>B</sub> = 0, T <sub>A</sub> = 100° C <sup>(1)</sup>		
I <sub>CB(ON)</sub>	On-State Collector Base				μA	
	4N47U, 4N47U (TX, TXV)	0.50	-	-		I <sub>F</sub> = 1.0 mA, V <sub>CE</sub> = 5.0 V, I <sub>B</sub> = 0
	4N47U, 4N47U (TX, TXV)	0.70	-	-		I <sub>F</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V, I <sub>B</sub> = 0, T <sub>A</sub> = -55° C <sup>(1)</sup>
	4N47U, 4N47U (TX, TXV)	0.50	-	-		I <sub>F</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V, I <sub>B</sub> = 0, T <sub>A</sub> = 100° C <sup>(1)</sup>
	4N48U, 4N48U (TX, TXV)	1.00	-	5		I <sub>F</sub> = 1.0 mA, V <sub>CE</sub> = 5.0 V, I <sub>B</sub> = 0
	4N48U, 4N48U (TX, TXV)	1.40	-	-		I <sub>F</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V, I <sub>B</sub> = 0, T <sub>A</sub> = -55° C <sup>(1)</sup>
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage				V	
	4N22U, 4N23U, 4N24U (TX, TXV)	-	-	0.30		I <sub>F</sub> = 20 mA, I <sub>C</sub> = 2.5 mA, I <sub>B</sub> = 0
	4N22U, 4N23U, 4N24U (TX, TXV)	-	-	0.30		I <sub>F</sub> = 20 mA, I <sub>C</sub> = 5.0 mA, I <sub>B</sub> = 0
H <sub>FE</sub>	DC Current Gain				V	
	4N22U, 4N22U (TX, TXV)	200	-	-		V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 10.0 mA, I <sub>F</sub> = 0 mA
	4N23U, 4N23U (TX, TXV)	300	-	-		V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 10.0 mA, I <sub>F</sub> = 0 mA
	4N24U, 4N24U (TX, TXV)	400	-	-		V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 10.0 mA, I <sub>F</sub> = 0 mA
R <sub>IO</sub>	Resistance (Input-to-Output)				Ω	
	4N47U, 4N48U, 4N49U (TX, TXV)	10 <sup>11</sup>	-	-		V <sub>I-O</sub> = ± 1,000 VDC <sup>(2)</sup>
C <sub>IO</sub>	Capacitance (Input-to-Output)			5	pF	V <sub>I-O</sub> = 0 V, f = 1.0 MHz <sup>(2)</sup>

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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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